

Application Data Sheet

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Application Information

Title Line One:	Epitaxial Silicon Wafer
Total Drawing Sheets:	4
Formal Drawings:	Yes
Application Type:	Utility
Docket Number:	86396

Representative Information

Registration Number One:	24,003
Registration Number Two:	22,839
Registration Number Three:	28,903
Registration Number Four:	27,429
Registration Number Five:	25,060
Registration Number Six:	22,053
Registration Number Seven:	27,466

Registration Number Eight 29,434
Registration Number Nine: 29,054
Registration Number Ten: 29,381
Registration Number Eleven: 34,044
Registration Number Twelve: 27,600
Registration Number Thirteen: 34,137
Registration Number Fourteen: 39,724
Registration Number Fifteen: 37,963
Registration Number Sixteen: 41,050
Registration Number Seventeen: 34,217

This application is based on application

Application One: PCT/JP00/04216

Filing Date: June 26, 2000

which is based on priority document

Japanese application no. 241187/1999

Filing Date: August 27, 1999